



Institut de Minéralogie et de Physique des Milieux Condensés Unité Mixte de Recherche 7590

Code 115, 4 Place Jussieu F-75252 Paris CEDEX 05

SÉMINAIRE Jeudi 31 mars, 10h30

Salle de Conférence, 4ème étage, Tour 22-23, Salle 1 IMPMC, Université P. et M. Curie, 4, Place Jussieu, 75005 Paris

Francesco MAURI

IMPMC

EVERYTHING YOU ALWAYS WANTED TO KNOW ABOUT RAMAN SPECTRA OF GRAPHENE (BUT WERE AFRAID TO ASK).

I will present an approach [1] that allows the ab-initio calculation of shape, intensity and position of defect-activated (D, D', D") and 2-phonon (D+D", 2D, 2D') resonant Raman peaks in graphene. We also reproduce the weaker 2-phonon bands, that involve acustic branches and that have recently been measured in graphene. Our (parameter-free) simulated spectra closely reproduce the measured spectra and their evolution with the laser energy and defect concentration. The detailed description of the Raman process allows us to identify the most relevant phonons, scattering events, and defect types involved in each peak.

[1] P. Venezuela, M. Lazzeri, F. Mauri, to be published.